



**PATENT**  
Atty. Docket No. ASC-044C1

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

APPLICANTS: Fitzgerald *et al.*

SERIAL NUMBER: 10/611,739                      ART UNIT: 2818

FILING DATE: July 1, 2003                      EXAMINER: Dung Anh Le

TITLE: METHOD OF FABRICATING CMOS INVERTER AND INTEGRATED  
CIRCUITS UTILIZING STRAINED SILICON SURFACE CHANNEL  
MOSFETS

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**RESPONSE**

Sir:

In response to the Office action mailed on February 18, 2004, Applicants request the Examiner to consider the following:

**Remarks** begin on page 2 of this paper; and

**Conclusion** begins on page 2 of this paper.